

MDMA1400C1600CC

Standard Rectifier Module

 $V_{RRM} = 1600 V$

 $I_{EAV} = 2x 700 A$

 $V_{\rm F} = 1.05 \, \rm V$

Common Cathode

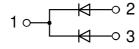
Part number

MDMA1400C1600CC



Backside: isolated





Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: ComPack

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling
- Phase Change Material available

Disclaimer Notice

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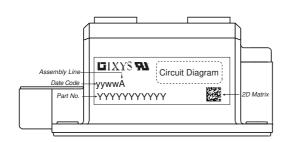
MDMA1400C1600CC

Rectifier					Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V _{RSM}	max. non-repetitive reverse bloc	king voltage	$T_{VJ} = 25^{\circ}C$			1700	V	
V _{RRM}	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			1600	V	
I _R	reverse current	V _R = 1600 V	$T_{VJ} = 25^{\circ}C$			500	μΑ	
		$V_R = 1600 \text{ V}$	$T_{VJ} = 150$ °C			20	mΑ	
V _F	forward voltage drop	I _F = 700 A	$T_{VJ} = 25^{\circ}C$			1.14	V	
		$I_F = 1400 \text{ A}$				1.35	٧	
		$I_F = 700 \text{ A}$	T _{VJ} = 125°C			1.05	٧	
		$I_F = 1400 A$				1.30	٧	
I FAV	average forward current	T _C = 100°C	T _{vJ} = 150°C			700	Α	
I _{F(RMS)}	RMS forward current	rectangular d = 0.5				1100	Α	
V _{F0}	threshold voltage		T _{vJ} = 150°C			0.78	٧	
r _F	slope resistance } for power	loss calculation only				0.35	mΩ	
R _{thJC}	thermal resistance junction to ca	ase				0.055	K/W	
R _{thCH}	thermal resistance case to heats	sink			0.02		K/W	
P _{tot}	total power dissipation		$T_{C} = 25^{\circ}C$			2270	W	
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			20.0	kA	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			21.6	kA	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150$ °C			17.0	kA	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			18.4	kA	
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			2.00	MA ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			1.94	MA^2s	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150$ °C			1.45	MA ² s	
		t = 8.3 ms; (60 Hz), sine	$V_R = 0 V$			1.40	MA ² s	
CJ	junction capacitance	$V_{R} = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		781		pF	



MDMA1400C1600CC

Package ComPack				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal				1200	Α
T _{VJ}	virtual junction temperature			-40		150	°C
T _{op}	operation temperature			-40		125	°C
T _{stg}	storage temperature			-40		125	°C
Weight					500		g
M _D	mounting torque			3		5	Nm
\mathbf{M}_{T}	terminal torque			12		14	Nm
d _{Spp/App}	araanaga diatanaa an aurfa	an Latriking diatanga through air	terminal to terminal	21.0			mm
$d_{Spb/Apb}$	creepage distance on surra	ce striking distance through air	terminal to backside	18.0			mm
V _{ISOL}	isolation voltage	t = 1 second	50/00 II	4800	4800		V
.002		t = 1 minute	50/60 Hz, RMS; lisoL ≤ 1 mA	4000			٧



Part description

M = Module

D = Diode
M = Standard Rectifier

A = (up to 1800V) 1400 = Current Rating [A]

C = Common Cathode 1600 = Reverse Voltage [V]

CC = ComPack

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDMA1400C1600CC	MDMA1400C1600CC	Box	3	520221

Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 150$ °C
$I \rightarrow V_0$)—[R _o]-	Rectifier		
V _{0 max}	threshold voltage	0.78		V
$R_{0 max}$	slope resistance *	0.16		$m\Omega$





Outlines ComPack

